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Haahr, Rasmus Grønbek; Duun, Sune; Birkelund, Karen; Raahauge, P.; Petersen, P.; Dam, Henrik Friis; Nørgaard, Lars; Thomsen, Erik Vilain

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A Novel Photodiode for Reflectance Pulse Oximetry in low-power applications

Rasmus G. Haahr, Sune Duun, Karen Birkelund, Palle Raahauge, Peter Petersen,
Henrik Dam, Lars N rgaard, and Erik V. Thomsen

Abstract—The amount of light collected is crucial for low-power applications of pulse oximetry. In this work a novel ring-shaped backside photodiode has been developed for a wearable reflectance pulse oximeter. The photodiode is proven to work with a dual LED with wavelengths of 660 nm and 940 nm. For the purpose of continuously monitoring vital signs of a human, a temperature sensor is integrated onto the chip containing the photodiode. This biomedical multisensor chip is made for integration into “the Electronic Patch”, an autonomous monitoring system for humans.

I. INTRODUCTION

Microsystems utilized in medico technology have a perspective of attaching small measuring or dosing systems on humans. These devices are small compared to conventional medical equipment which force patients to stay at hospitals and often also to lie in bed such that instruments can be attached. This is both inconvenient for the patients and expensive for the health care system. Small integrated systems allow patients to keep their mobility and open up for home care nursing using telemedicine solutions.

Pulse oximetry is an intensively used non-invasive method for measuring the arterial oxygen saturation (SpO_2) with the purpose of detecting hypoxemia which can result in brain damage or death.

We have previously described a new patient monitoring system - the Electronic Patch (EP) [1], which is an in vivo platform for continuously monitoring body parameters, Fig. 1. The system is attached to the body with a sticking patch containing sensors, an ASIC solution for signal processing, and wireless communication based on a SWM1601 radio chip. The electronic patch is powered by a CR-2025 coin battery and is intended for use on heart disease patients hospitalized in their own home and for professionals in high risk working environments.

In this work we have developed a pulse oximetry sensor for the electronic patch. Since the patch is planar, reflection mode pulse oximetry is employed. The problem of artifacts in the signal due to motion is often mentioned in the literature [2]. In the EP the photodiode and light source are fixed to the body by a sticking patch which minimizes the motion artifacts due to the movement of the photo detector and light source relative to each other.

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The authors are all with the Department of Micro and Nanotechnology, Technical University of Denmark, 2800 Kgs. Lyngby, Denmark. rasmus.haahr@mic.dtu.dk

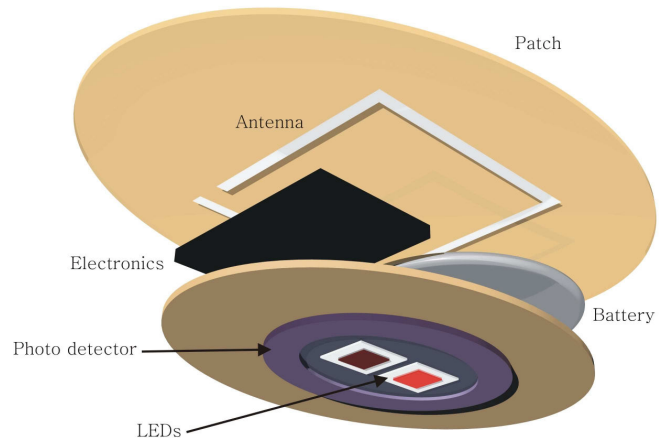


Fig. 1. Illustration of the developed electronic patch. The patch has a size of 20 cm² and is 5 mm thick.

In the literature reflection mode pulse oximetry sensors have previously been reported: Studies have been conducted using one photo detector and one light source by Mendelson *et al.* [3] and Dassel *et al.* [4]. An early design using multiple photo detectors with a single light source was made by Mendelson *et al.* [5] and more recently power optimization has been studied [6]. Other design approaches have also been studied: Takatani *et al.* have studied a design using 20 LEDs placed concentrically around a single photo detector [7], [8]; however, these designs were used to study the quality of the signal and not low power applications which is the case with the EP. A finger-ring type of pulse oximeter intended for ambulatory use has been developed and studied by both Asada *et al.* [9], [10] and Mendelson *et al.* [11].

A physiologically monitoring system worn on the wrist for measuring several body parameters including SpO_2 has been reported by Yoo [12]. This system uses a conventional finger probe attached on the finger which is connected by a wire to the monitoring unit on the wrist.

We report a pulse oximeter based on a ring-shaped photodiode with a hole in the middle for the light source as shown in Fig. 1. The photodiode collects backscattered light from the tissue all the way around the light source, therefore as much as possible of the backscattered light will be collected by the photodiode. This allows for a very low LED drive current which will lower the power consumption by the device. Furthermore, we have integrated an anti-reflection optical filter on the photodiode for enhanced sensitivity. In

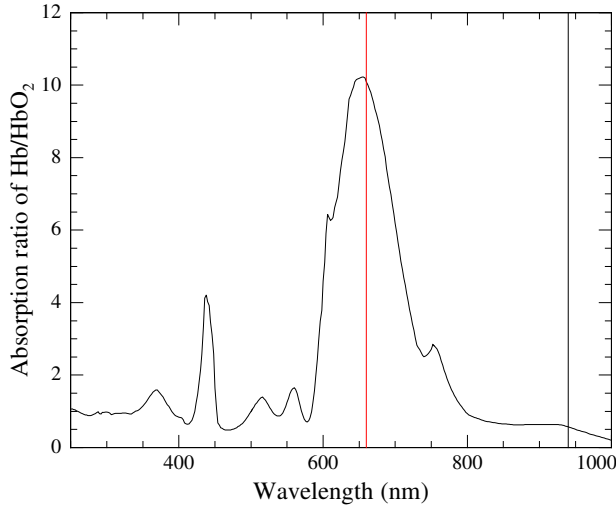


Fig. 2. Ratio between the absorption coefficients of de-oxygenated and oxygenated hemoglobin. The plot is based on data from [13].

addition to the photodiode the chip also contains a thermistor for measuring the body surface temperature, thereby creating a multisensor for medical purposes on a single chip.

A. Pulse Oximetry

Pulse oximetry is a spectrophotometric method for non-invasive measurement of the arterial oxygen saturation and can generally be performed in either transmission or reflection modes. In the first, light is transmitted through the tissue e.g. a finger and in the latter light is backscattered from the tissue. The method relies on a difference in the absorption spectra of oxygenated and de-oxygenated hemoglobin. The ratio between these is seen in Fig. 2. It is seen that the ratio has a peak at approximately 660 nm and at higher wavelengths the ratio is lower than one. Two wavelengths must be used since we have two absorption spectra. Conventionally, 660 nm (red) and 940 nm (IR) are used since the absorption ratio is large and small at those wavelengths respectively. This minimizes the uncertainty of the SpO_2 measurement. By rapidly blinking (a frequency much higher than the heart beat rate) with the red and IR light sources two photoplethysmograms (optical recordings of the cardiovascular cycle), one for each wavelength, are recorded. The SpO_2 is a function of the measured magnitude at the systolic and diastolic states of the two photoplethysmograms:

$$\text{SpO}_2 \sim \ln \left(\frac{\text{red}_{\text{systole}}}{\text{red}_{\text{diastole}}} \right) / \ln \left(\frac{\text{IR}_{\text{systole}}}{\text{IR}_{\text{diastole}}} \right) \quad (1)$$

where $\text{red}_{\text{systole}}$ and $\text{red}_{\text{diastole}}$ are the magnitudes of the red light measured at the systolic state and diastolic state respectively and likewise for $\text{IR}_{\text{systole}}$ and $\text{IR}_{\text{diastole}}$. However, measurement of SpO_2 normally relies on empirical calibration [2].

II. DESIGN OF CHIP AND PHOTODIODE

The multisensor chip with the photodiode and thermistor developed in this work has several novel features. The front-

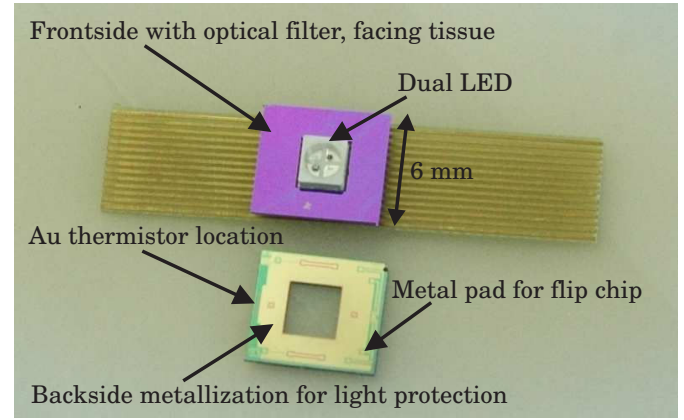


Fig. 3. Picture of the chip with the ring-shaped photodiode and the Au thermistor. The diode junction is made on the opposite site of the light entrance to avoid metallization and wiring to the frontside facing the tissue.

and backside of the chip together with a Ledtronics dual LED with wavelengths of 660 nm and 940 nm is seen in Fig. 3. The chip has a hole in the middle of $3.3 \times 3.6 \text{ mm}^2$ which fits to the dual LED. The photodiode is defined as a single ring-shaped structure concentrically around the hole with an inner radius of 3.29 mm and an outer radius of 4.07 mm yielding an active area of 18 mm^2 . The actual diode junction is made on the opposite side of the light entrance to avoid metallization and wiring to the surface facing the skin. This therefore creates a backside photodiode where photons are absorbed by generation of minority carriers in the base substrate and these then diffuse to the diode junction. The diode is fabricated in p-type silicon since minority electrons have approximately a factor of 2 higher diffusivity compared to holes.

The front side of the chip has an anti-reflection filter which allows transmission of 98 % for wavelengths of 660 nm and 940 nm which enhance the sensitivity of the device, Fig. 4. The filter is developed so that other wavelengths are suppressed to screen off stray light. The peak at 515 nm is less important due to a shorter photon penetration depth in the base material and a high absorbance by tissue at shorter wavelengths [13]. The filter is made by a stack of 50 nm silicon oxide and 550 nm silicon nitride.

An Au metal thermistor, made in a meander structure with a total length of 17.8 cm, a width of $3 \mu\text{m}$ and a height of 200 nm, is integrated on the chip for measurement of body temperature on the skin surface.

III. RESULTS

A. Diode characteristics

A current-voltage characteristic for the photodiode is shown in Fig. 5. The photodiode has a forward saturation current density of $J_s = 167 \text{ pA/cm}^2$ and an ideality factor of $n = 1.19$ showing that the diode is close to ideal. Some generation current is observed as seen from the deviation from the fit in the range 0 to 0.12 V. The series resistance of the mounted chip on a printed circuit board is $R_s = 84 \Omega$. We have obtained a quantum efficiency of 0.65 and 0.7

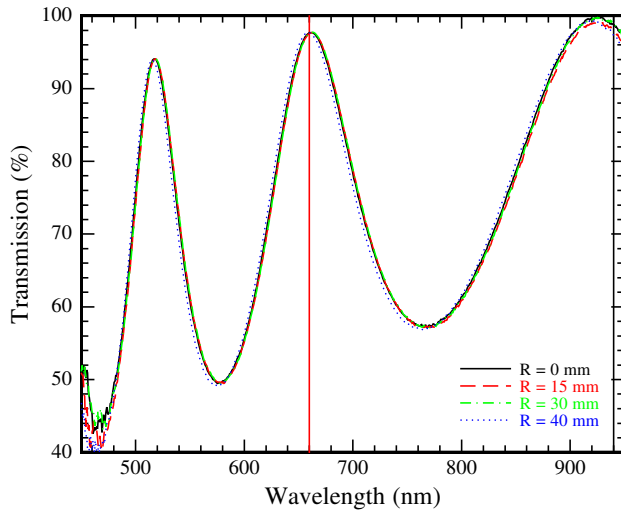


Fig. 4. Transmission of the SiO₂ and SiN interference filter measured with a Filmtrek reflectometer. The transmission uniformity across a wafer is seen to be good since there is no significant deviation in transmission between the four plots measured at a radius, R, from the wafer center.

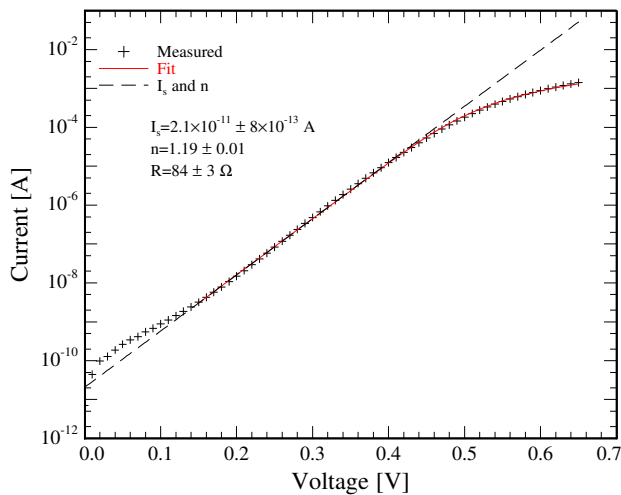


Fig. 5. Current-voltage characteristic of the fabricated photodiode. The photodiode ring has inner radius 3.29 mm and outer radius 4.07 mm yielding an active area of 18 mm².

at wavelengths of 660 nm and 940. This is reasonable for the current design of the photodiode, but less than that of high-end commercial photodiodes and solar cells.

B. Au thermistor characteristics

A measurement of resistance as a function of temperature is shown in Fig. 6. The thermistor is found to have a resistance of 13.6 kΩ at 37°C and a temperature of resistance ratio (TCR) of $2.6 \cdot 10^{-3} \text{K}^{-1}$. This is a little less than that of pure Au ($3.4 \cdot 10^{-3} \text{K}^{-1}$) and it is believed to be due to a non lattice structure of the deposited Au compared to bulk Au.

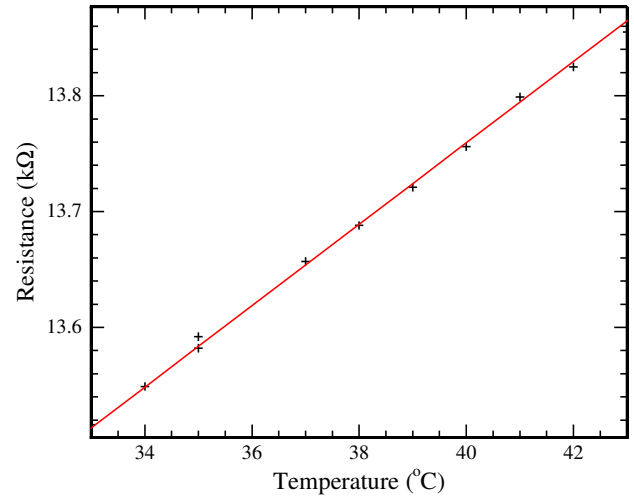


Fig. 6. Resistance dependence of temperature for the Au thermistor.

C. Photoplethysmograms

The fabricated photodiode packaged with a dual LED, as shown in Fig. 3, has been tested as a pulse oximeter on a test person's pulp of the left hand index finger. The result is shown in Fig. 7. The two recorded photoplethysmograms for the red and IR light both clearly display the cardiovascular cycle. The data are obtained by blinking with the red and IR LED elements with a frequency of 4 kHz and 180° out of phase. Data are sampled with 8 kHz. The data collection is done using Labview and the data have been processed with a moving average using a rectangular window with a width of 401 data points. The photoplethysmograms are also corrected for drift. The photoplethysmograms using red and IR light are plotted against the left and right abscissas respectively. From (1) a ratio of 0.7 is obtained. In [2] a simple theoretical model for the calibration is derived. Using this it is found that the ratio in (1) of 0.7 corresponds to a SpO₂ of approximately 85 %. Even though the pulse oximeter has not been empirically calibrated in a clinical setup the result indicates that it works properly.

IV. FABRICATION

The process fabrication sequence is shown in Fig. 8. The starting point is a 300 μm thick 4" p-type silicon floatzone wafer with a boron doping of $5 \cdot 10^{15} \text{cm}^{-3}$ and 1 ms minority carrier lifetime. A 765 nm thermal wet silicon oxide is grown. Alignment marks and the opening of the SiO₂ at the photodiode area are done by photolithography and etching in buffered hydrofluoric acid (bHF) with the backside protected by a photoresist. A 1 h phosphor pre-deposition is done at 1000°C. Another wet oxidation for 1 h at 1000°C is performed to make alignment marks and a masking silicon oxide for boron pre-deposition at the contacting areas. The masking silicon oxide are opened with bHF using photolithography. The boron pre-deposition is performed for 1 h at 975°C giving a 1 μm deep doping profile, Fig. 8(a). The masking silicon oxide is removed in bHF and a 50 nm dry silicon

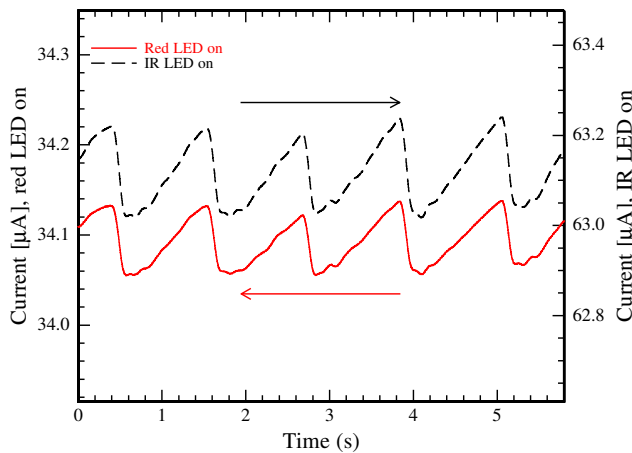


Fig. 7. Photoplethysmograms measured with the developed ring-shaped photodiode.

oxide is grown on both sides of the wafer. On the skin side it serves as the first layer for the optical filter and to give a low surface recombination velocity. On the side of the diode junction it serves as electrical isolation. Hereafter, a 550 nm PECVD silicon nitride is deposited for the second filter layer and electric passivation, Fig. 8(b). Contact holes are defined using photolithography and opened with bHF. Contacts, Au thermistor, and metallization for reflection of light from the top side of the wafer are made by evaporation of 20 nm Cr and 200 nm Au using an Alcatel e-beam evaporator, Fig. 8(c). The chromium is used to give a good adhesion to the silicon nitride. In the last step the hole for the dual LED is defined using backside photolithography and a hole is etched through the wafer from the skin side (lower side on Fig. 8(d)) with a STS Advanced Silicon Etcher, ASE.

V. CONCLUSION AND FUTURE WORKS

A. Conclusions

A multisensor chip for measurements of temperature and pulse oximetry (SpO_2) is reported. The chip has a novel ring-shaped backside photodiode with a special designed optical filter for pulse oximetry in low-power applications, and an Au thermistor. The design and fabrication of the photodiode and the thermistor has been presented. The photodiode and the thermistor has been characterized and proven to work as a pulse oximeter; however, more advanced photodiode designs could be considered to further enhance the quantum efficiency. The chip has been packaged together with a dual LED of 660 nm and 940 nm into a compact pulse oximeter which is compatible with integration into the Electronic Patch, Fig. 1.

B. Future Works

The pulse oximeter should be completely integrated into the Electronic Patch for optimizing the systems with respect to measuring sites on the body and power consumption. The monitoring systems should then be evaluated in clinical trials.

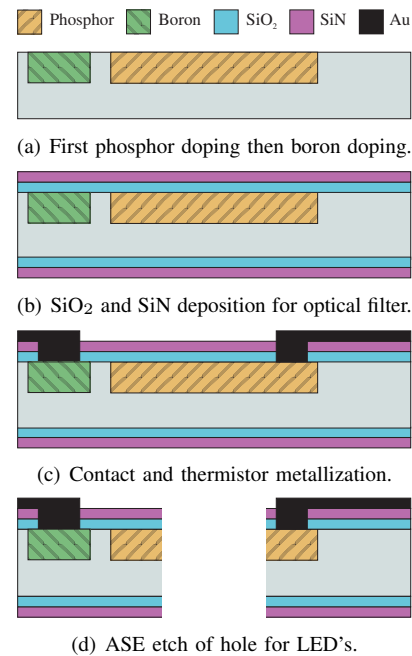


Fig. 8. Process sequence for the ring shaped photodiode for pulseoximetry.

VI. ACKNOWLEDGMENTS

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